

TOSHIBA Bi-CMOS Digital Integrated Circuit Silicon Monolithic

TB2922HQ

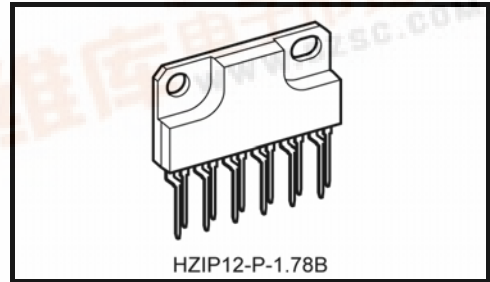
Dual Audio Power Amplifier

The TB2922HQ is 2ch BTL audio amplifier for TV or home audio applications.

It includes and the pure complementary P-ch and N-ch DMOS output stage.

The package is CPP (Compact Power Package).

It is built-in standby function, muting function various kinds of protectors.



Weight: 4.04 g (typ.)

Features

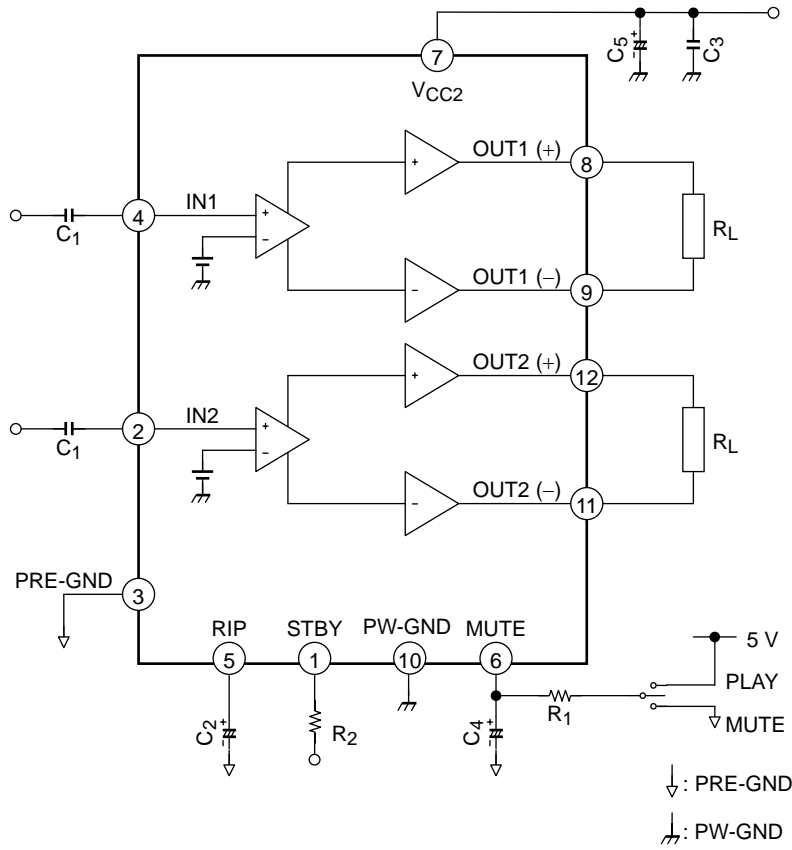
- High power output
 - : $P_{OUT(1)} = 22\text{ W (typ)}$
($V_{CC} = 18\text{ V}$, $R_L = 8\ \Omega$, $f = 1\text{ kHz}$, $\text{THD} = 10\%$)
 - : $P_{OUT(2)} = 37\text{ W (typ)}$
($V_{CC} = 16\text{ V}$, $R_L = 4\ \Omega$, $f = 1\text{ kHz}$, $\text{THD} = 10\%$)
 - : $P_{OUT(3)} = 46\text{ W (typ)}$
($V_{CC} = 26\text{ V}$, $R_L = 8\ \Omega$, $f = 1\text{ kHz}$, $\text{THD} = 10\%$)
 - : $P_{OUTMAX(1)} = 72\text{ W (typ)}$
($V_{CC} = 26\text{ V}$, $R_L = 8\ \Omega$, $f = 1\text{ kHz}$, Max Power)
- Low distortion ratio : $\text{THD} = 0.02\% \text{ (typ)}$
- Low noise : $V_{no} = 0.16\ \mu\text{ Vrms (typ)}$
($V_{CC} = 18\text{ V}$, $R_L = 8\ \Omega$, $R_g = 0\ \Omega$, $\text{BW} = 20\text{ Hz} \sim 20\text{ kHz}$)
- Low outside parts
- Built-in standby switch function (pin 1)
- Built-in muting function (pin 6)
- Built-in various protection circuits:
Thermal shut down, overvoltage, out to GND, out to VCC, out to out short speaker burned
- Operating supply voltage
 - : $V_{CC(opr)} = 9\text{ to }26\text{ V (}R_L = 8\ \Omega\text{)}$
 - : $V_{CC(opr)} = 9\text{ to }18\text{ V (}R_L = 4\ \Omega\text{)}$

Note 1: Install the device correctly. Otherwise, the device or system may be degraded, damaged or even destroyed.

Note 2: The protection features are intended to avoid output short-circuits or other abnormal conditions temporarily. It is not guaranteed that they will prevent the IC from being damaged. Exposure to conditions beyond the guaranteed operating ranges may not activate the protection features, resulting in an IC damage due to output short-circuits.

Note 3: If HBM ESD(condition; $100\text{ pF}/1.5\text{ k}\Omega$) of under -1900 V is applied to pin 2 or pin 4 in case that pin3 is GND, this product may break down.

Block Diagram



Some of the functional blocks, circuits, or constants in the block diagram may be omitted or simplified for explanatory purpose.

Caution and Application Method (Description is made only on the single channel)

1. Voltage Gain Adjustment

This IC has no NF (negative feedback) Pins. Therefore, the voltage gain can not be adjusted, but it makes the device a space and total costs saver.

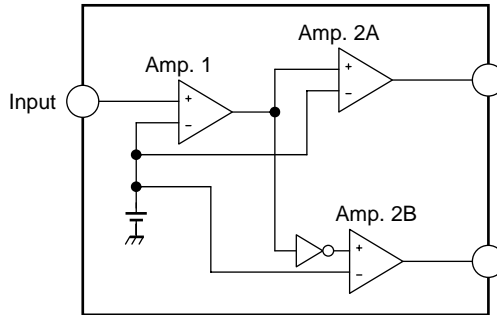


Figure 1 Block Diagram

The voltage gain of amp.1 : $GV_1 = 8\text{dB}$

The voltage gain of amp.2A, B : $GV_2 = 20\text{dB}$

The voltage gain of BTL connection: $GV(\text{BTL}) = 6\text{dB}$

Therefore, the total voltage gain is decided by expression below.

$$GV = GV_1 + GV_2 + GV(\text{BTL}) = 8 + 20 + 6 = 34\text{dB}$$

2. Standby SW Function (pin 1)

By means of controlling pin 1 (standby pin) to High and Low, the power supply can be set to ON and OFF. The threshold voltage of pin 1 is set at about $3 V_{BE}$ (typ.), and the power supply current is about $2 \mu\text{A}$ (typ.) in the standby state.

Control Voltage of Pin 4: V_{SB}

Stand-by	Power	V_{SB} (V)
ON	OFF	0 to 0.5
OFF	ON	2.5 to 6

When changing the time constant of pin 1, check the pop noise.

Advantage of Standby SW

- (1) Since V_{CC} can directly be controlled to ON or OFF by the microcomputer, the switching relay can be omitted.
- (2) Since the control current is microscopic, the switching relay of small current capacity is satisfactory for switching.

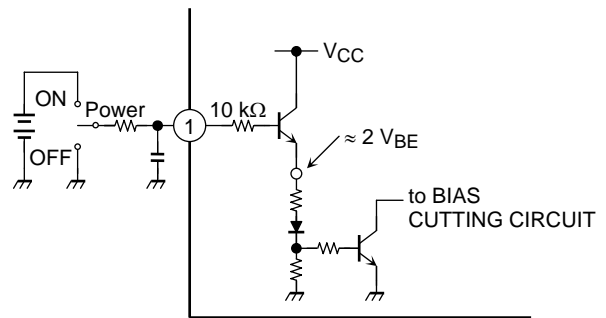


Figure 2 With pin 1 set to High, Power is turned ON

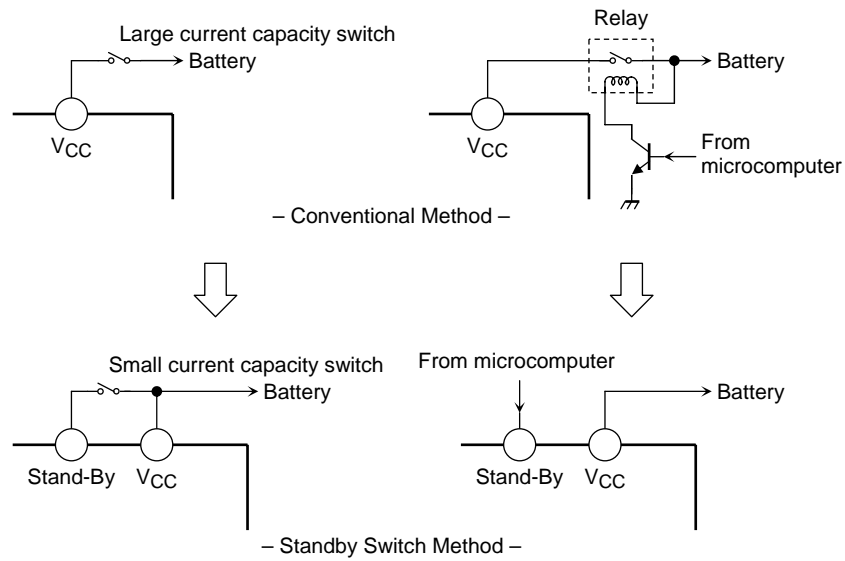


Figure 3

3. Muting Function (pin 6)

Audio muting function is enabled when pin 6 is Low. When the time constant of the muting function is determined by R_1 and C_4 , it should take into account the pop noise. The pop noise, which is generated when the power or muting function is turned ON/OFF, will vary according to the time constant. (Refer to Figure4)

The pin 6 is designed to operate off 5 V so that the outside pull-up resistor R_1 is determined on the basis of this value:

ex) When control voltage is changed in to 6 V from 5 V.

$$6 \text{ V}/5 \text{ V} \times 47 \text{ k} = 56 \text{ k}$$

Additionally, as the V_{CC} is rapidly falling, the IC internal low voltage muting operates to eliminate the large pop noise basically.

The low voltage muting circuit pull 200 μA current into the IC so that the effect of the internal low voltage muting does not become enough if the R_1 is too small value.

To obtain enough operation of the internal low voltage muting, a series resistor, R_1 at pin 6 should be 47 $\text{k}\Omega$ or more.

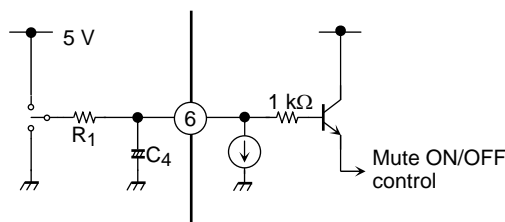


Figure 4 Muting Function

4. Pop Noise Suppression

The pop noise which is generated when the muting function is turned ON/OFF will vary according to the time constant of C4.

The greater the capacitance, the lower the pop noise. Note that the time from when the mute control signal is applied to C4 to when the muting function is turned ON/OFF will be longer.

5. External Component Constants

Component Name	Recommended Value	Purpose	Effect	
			Lower than recommended value	Higher than recommended value
C1	0.22 μ F	To eliminate DC	Cut-off frequency is increased	Cut-off frequency is reduced
C2	10 μ F	To reduce ripple	Powering ON/OFF is faster	Powering ON/OFF takes longer
C3	0.1 μ F	To provide sufficient oscillation margin	Reduces noise and provides sufficient oscillation margin	
C4	1 μ F	To reduce pop noise	High pop noise. Duration until muting function is turned ON/OFF is short	Low pop noise. Duration until muting function is turned ON/OFF is long
C5	3900 μ F	Ripple filter	Power supply ripple filtering	

Absolute maximum ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
DC supply voltage	V _{CC (DC)}	28	V
Operation supply voltage	V _{CC (opr)}	26	V
Power dissipation	P _{D (Note 4)}	62.5	W
Operation temperature	T _{opr}	-40 to 85	°C
Storage temperature	T _{stg}	-55 to 150	°C

Note 4: Package thermal resistance $\theta_{j-T} = 2^{\circ}\text{C}/\text{W}$ (typ.) (Ta = 25°C, with infinite heat sink)

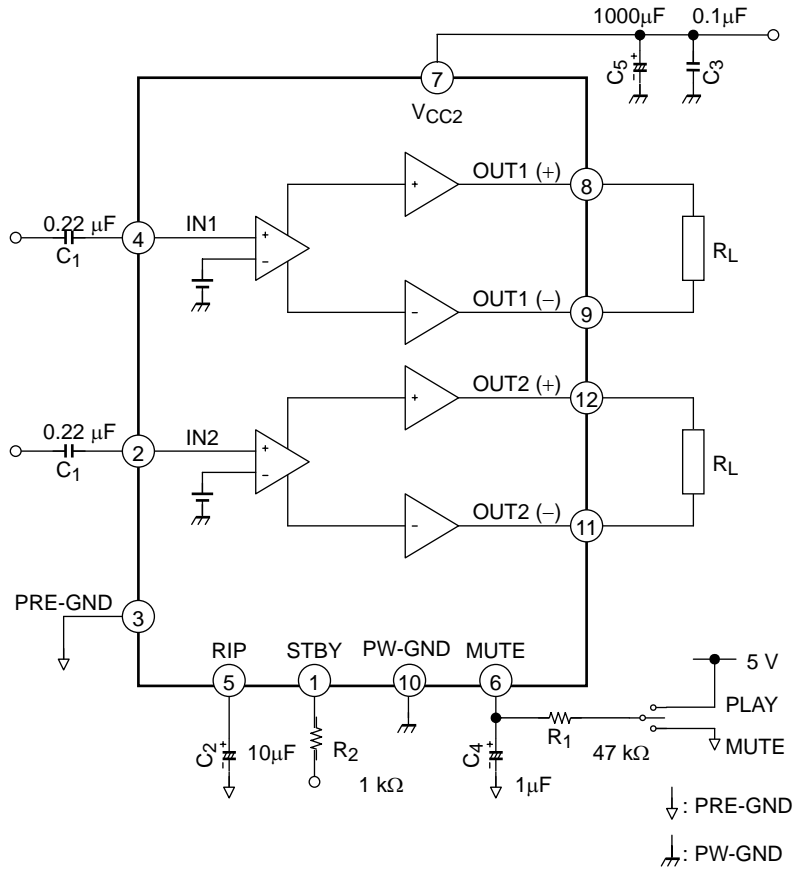
The absolute maximum ratings of a semiconductor device are a set of specified parameter values, which must not be exceeded during operation, even for an instant. If any of these rating would be exceeded during operation, the device electrical characteristics may be irreparably altered and the reliability and lifetime of the device can no longer be guaranteed. Moreover, these operations with exceeded ratings may cause break down, damage and/or degradation to any other equipment. Applications using the device should be designed such that each absolute maximum rating will never be exceeded in any operating conditions. Before using, creating and/or producing designs, refer to and comply with the precautions and conditions set forth in this documents.

Electrical Characteristics

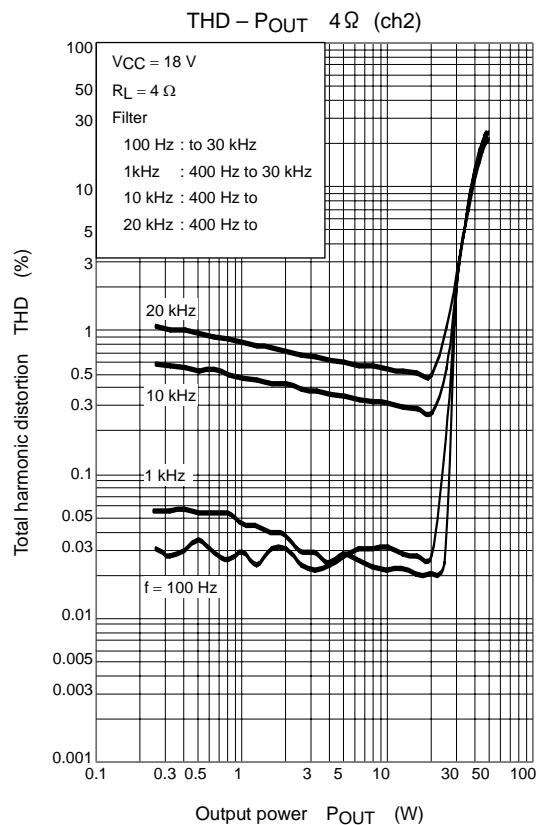
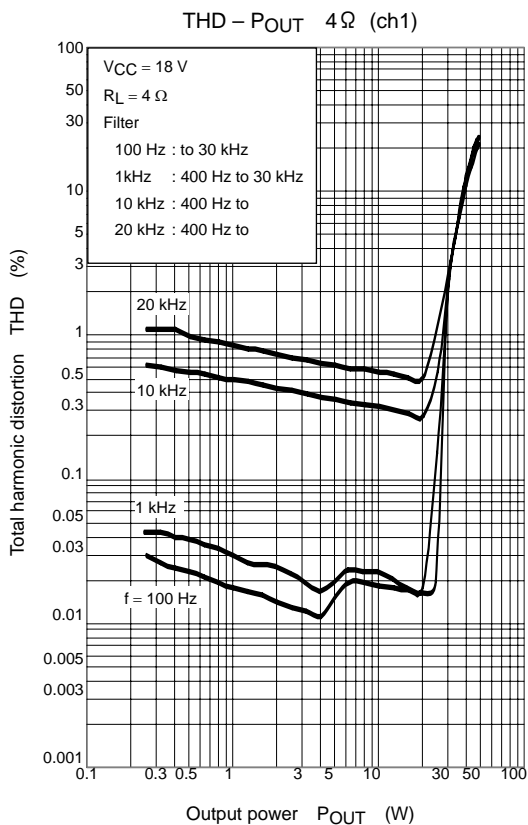
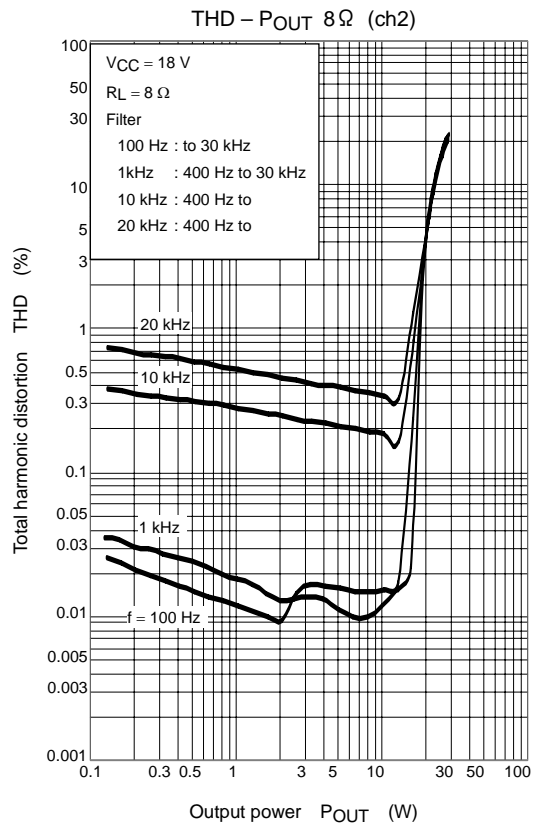
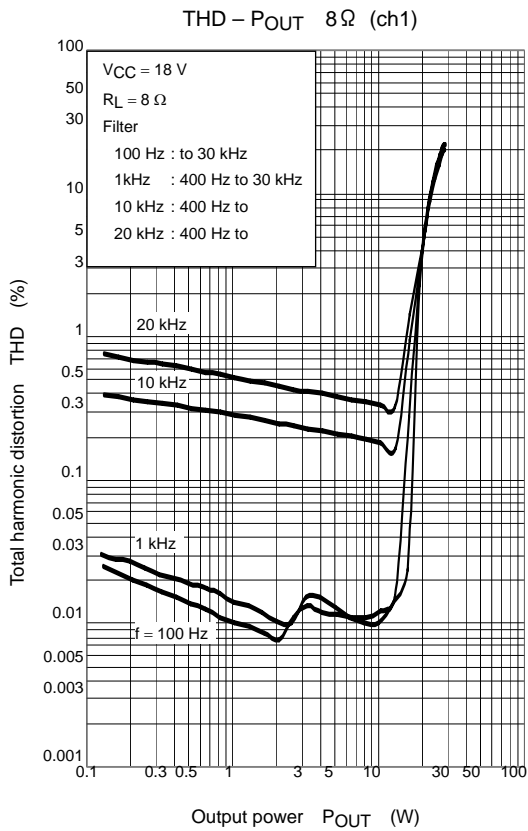
(unless otherwise specified, V_{CC} = 18 V, f = 1 kHz, R_L = 8 Ω, Ta = 25°C)

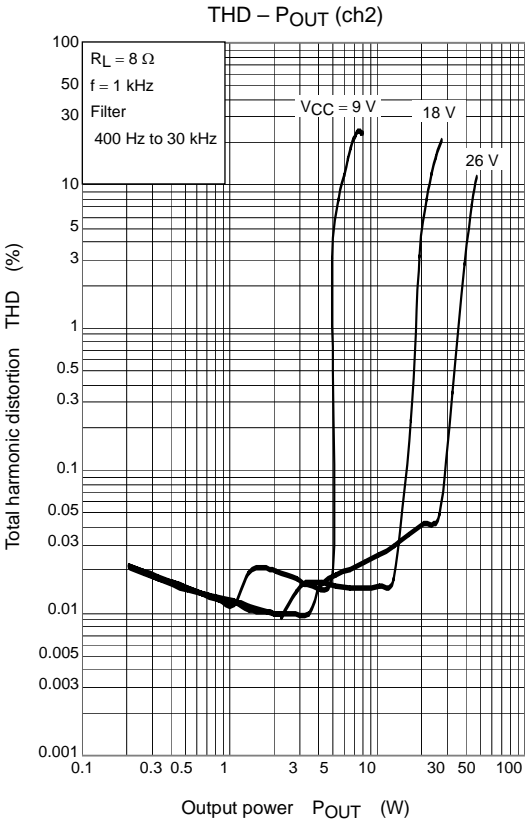
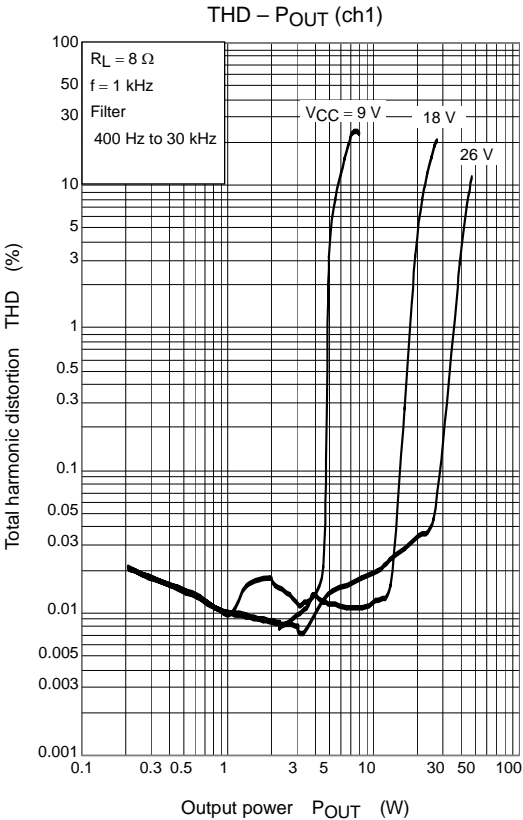
Characteristics	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Quiescent current	I _{CCQ}	—	V _{IN} = 0	—	80	150	mA
Output power	P _{OUT (1)}	—	THD = 10%	21	22	—	W
	P _{OUT (2)}	—	THD = 10%, R _L =4Ω	—	37	—	
	P _{OUT (3)}	—	V _{CC} = 26 V, THD = 10%	—	46	—	
	P _{OUT MAX (1)}	—	V _{CC} = 26V, Max POWER	—	72	—	
Total harmonic distortion	THD	—	P _{OUT} = 4 W	—	0.02	0.20	%
Voltage gain	G _V	—	V _{OUT} = 0.775 V _{rms}	32	34	36	dB
Voltage gain ratio	ΔG _V	—	V _{OUT} = 0.775 V _{rms}	-1.0	0	1.0	dB
Output noise voltage	V _{NO}	—	R _g = 0 Ω, BW = 20 Hz~20 kHz	—	180	250	μV _{rms}
Ripple rejection ratio	R.R.	—	f _{rip} = 100 Hz, R _g = 620 Ω V _{rip} = 0.775 V _{rms}	40	50	—	dB
Cross talk	C.T.	—	R _g = 620 Ω V _{OUT} = 0.775 V _{rms}	—	65	—	dB
Output offset voltage	V _{OFFSET}	—	—	-250	0	250	mV
Input resistance	R _{IN}	—	—	—	30	—	kΩ
Standby current	I _{SB}	—	Standby condition	—	1	10	μA
Standby control voltage	V _{SB H}	—	POWER: ON	2.5	—	6.0	V
	V _{SB L}	—	POWER: OFF	0	—	0.5	
Mute control voltage	V _{M H}	—	MUTE: OFF	2.5	—	6.0	V
	V _{M L}	—	MUTE: ON, R ₁ = 47 kΩ	0	—	0.5	
Mute attenuation	ATT M	—	MUTE: ON V _{OUT} = 10 V _{rms} →Mute: OFF	85	100	—	dB

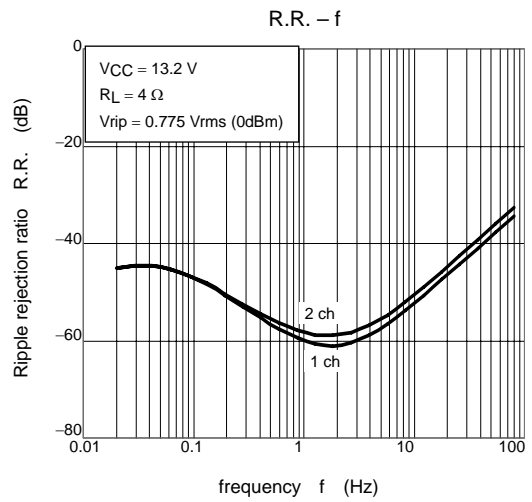
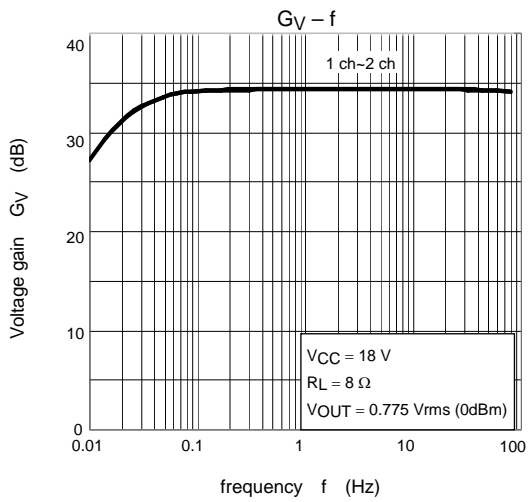
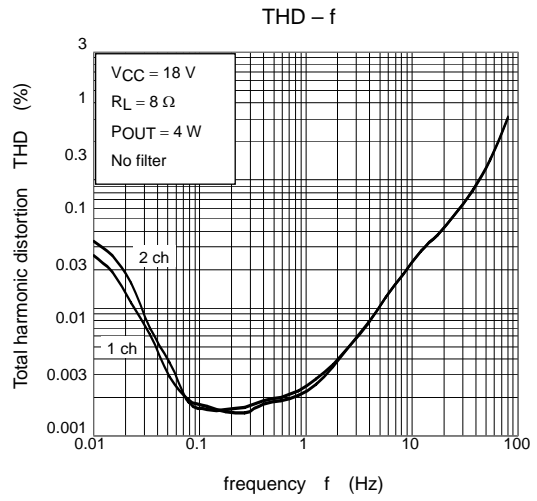
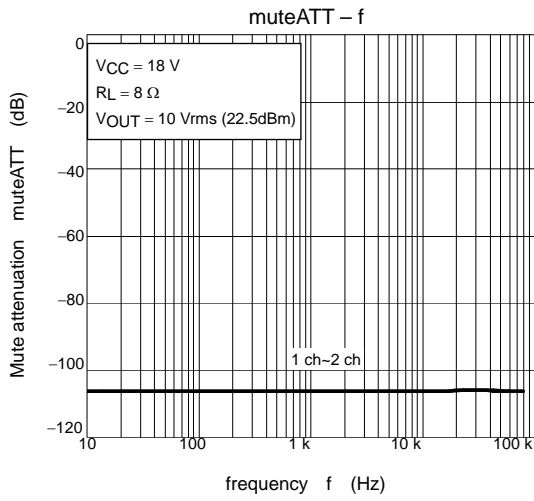
Test Circuit

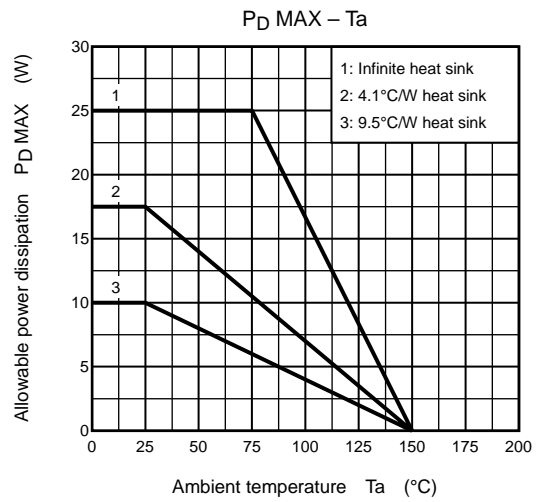
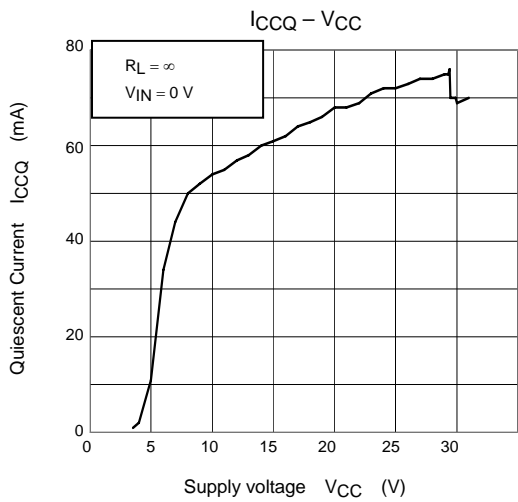
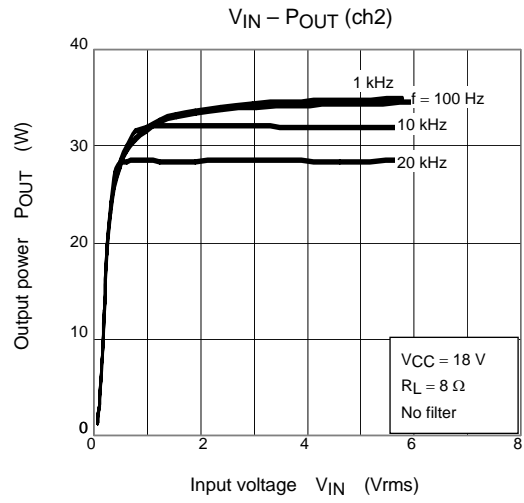
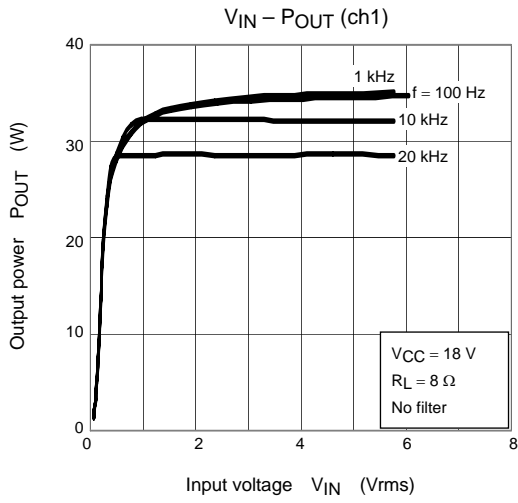


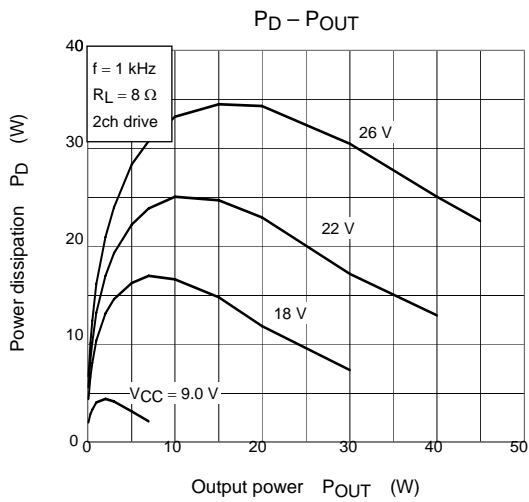
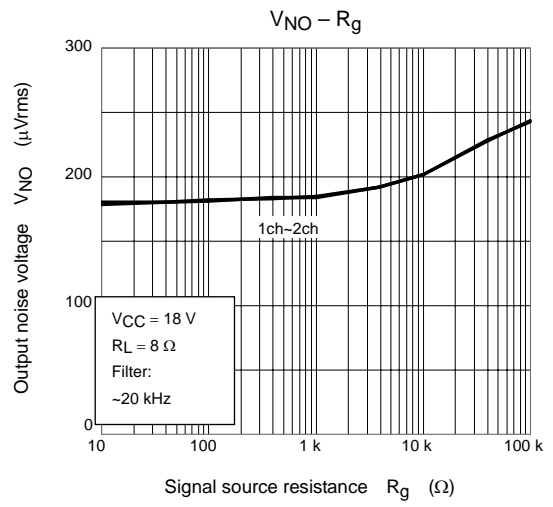
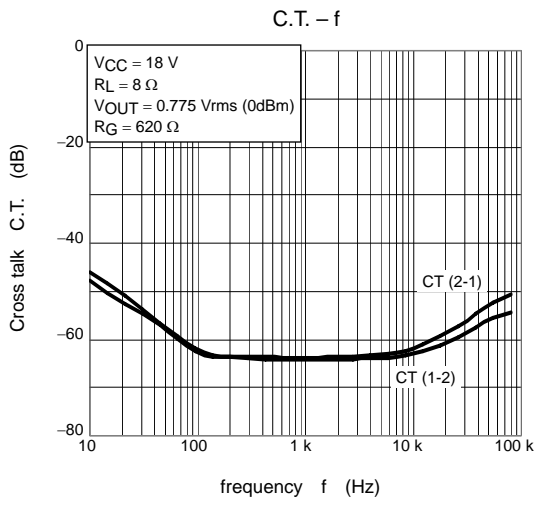
Components in the test circuits are only used to obtain and confirm the device characteristics.
 These components and circuits do not warrant to prevent the application equipment from malfunction or failure.







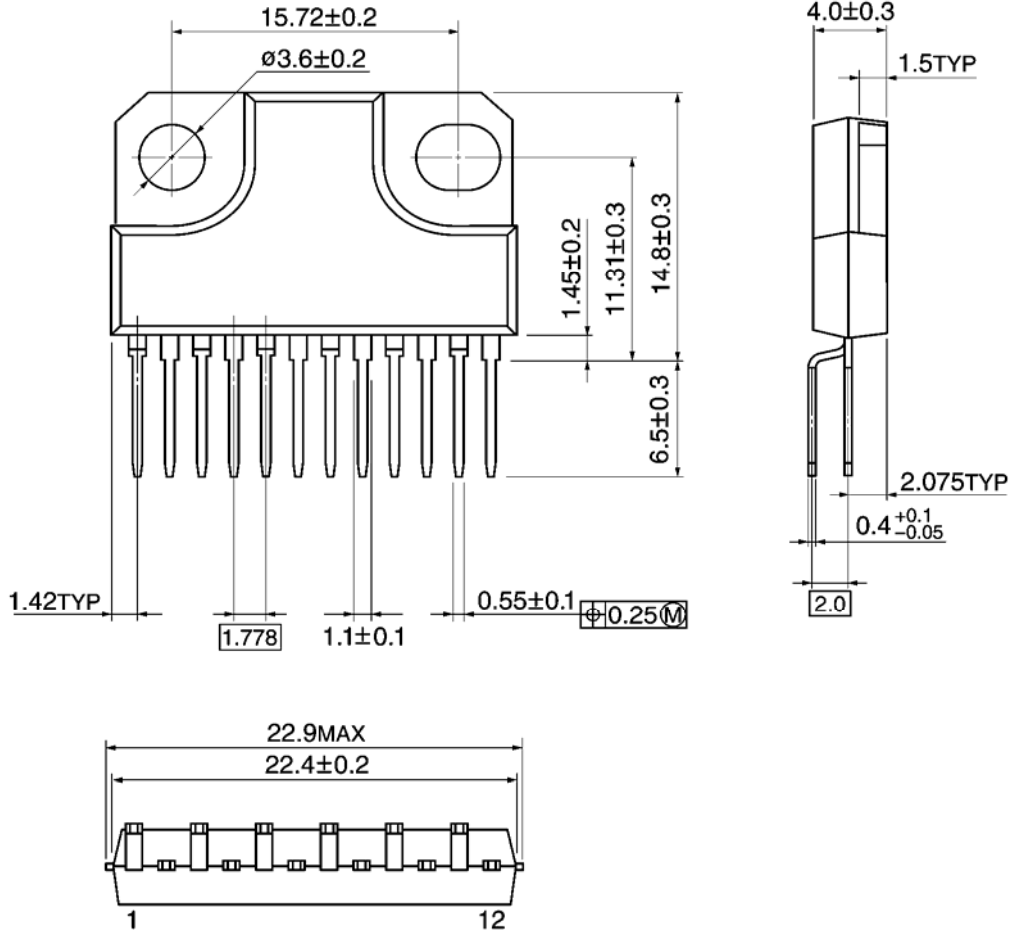




Package Dimensions

HZIP12-P-1.78B

Unit: mm



Weight: 4.04 g (typ.)

- Use an appropriate power supply fuse to ensure that a large current does not continuously flow in case of over current and/or IC failure. The IC will fully break down when used under conditions that exceed its absolute maximum ratings, when the wiring is routed improperly or when an abnormal pulse noise occurs from the wiring or load, causing a large current to continuously flow and the breakdown can lead smoke or ignition. To minimize the effects of the flow of a large current in case of breakdown, appropriate settings, such as fuse capacity, fusing time and insertion circuit location, are required.
- If your design includes an inductive load such as a motor coil, incorporate a protection circuit into the design to prevent device malfunction or breakdown caused by the current resulting from the inrush current at power ON or the negative current resulting from the back electromotive force at power OFF. For details on how to connect a protection circuit such as a current limiting resistor or back electromotive force adsorption diode, refer to individual IC datasheets or the IC databook. IC breakdown may cause injury, smoke or ignition.
- Use a stable power supply with ICs with built-in protection functions. If the power supply is unstable, the protection function may not operate, causing IC breakdown. IC breakdown may cause injury, smoke or ignition.
- Carefully select external components (such as inputs and negative feedback capacitors) and load components (such as speakers), for example, power amp and regulator. If there is a large amount of leakage current such as input or negative feedback condenser, the IC output DC voltage will increase. If this output voltage is connected to a speaker with low input withstand voltage, overcurrent or IC failure can cause smoke or ignition. (The over current can cause smoke or ignition from the IC itself.) In particular, please pay attention when using a Bridge Tied Load (BTL) connection type IC that inputs output DC voltage to a speaker directly.
- Over current Protection Circuit
Over current protection circuits (referred to as current limiter circuits) do not necessarily protect ICs under all circumstances. If the Over current protection circuits operate against the over current, clear the over current status immediately. Depending on the method of use and usage conditions, such as exceeding absolute maximum ratings can cause the over current protection circuit to not operate properly or IC breakdown before operation. In addition, depending on the method of use and usage conditions, if over current continues to flow for a long time after operation, the IC may generate heat resulting in breakdown.
- Thermal Shutdown Circuit
Thermal shutdown circuits do not necessarily protect ICs under all circumstances. If the Thermal shutdown circuits operate against the over temperature, clear the heat generation status immediately. Depending on the method of use and usage conditions, such as exceeding absolute maximum ratings can cause the thermal shutdown circuit to not operate properly or IC breakdown before operation.
- Heat Radiation Design
When using an IC with large current flow such as power amp, regulator or driver, please design the device so that heat is appropriately radiated, not to exceed the specified junction temperature (T_j) at any time and condition. These ICs generate heat even during normal use. An inadequate IC heat radiation design can lead to decrease in IC life, deterioration of IC characteristics or IC breakdown. In addition, please design the device taking into consideration the effect of IC heat radiation with peripheral components.
- Installation to Heat Sink
Please install the power IC to the heat sink not to apply excessive mechanical stress to the IC. Excessive mechanical stress can lead to package cracks, resulting in a reduction in reliability or breakdown of internal IC chip. In addition, depending on the IC, the use of silicon rubber may be prohibited. Check whether the use of silicon rubber is prohibited for the IC you intend to use, or not. For details of power IC heat radiation design and heat sink installation, refer to individual technical datasheets or IC databooks.

About solderability, following conditions were confirmed

- Solderability

- (1) Use of Sn-63Pb solder Bath

- solder bath temperature = 230°C
 - dipping time = 5 seconds
 - the number of times = once
 - use of R-type flux

- (2) Use of Sn-3.0Ag-0.5Cu solder Bath

- solder bath temperature = 245°C
 - dipping time = 5 seconds
 - the number of times = once
 - use of R-type flux

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- This product generates heat during normal operation. However, substandard performance or malfunction may cause the product and its peripherals to reach abnormally high temperatures.
The product is often the final stage (the external output stage) of a circuit. Substandard performance or malfunction of the destination device to which the circuit supplies output may cause damage to the circuit or to the product.